Physics 121 - Electricity and Magnetism Lecture 06 - Capacitance

Y&F Chapter 24 Sec. 1 - 6

- Overview
- Definition of Capacitance
- Calculating the Capacitance
- Parallel Plate Capacitor
- Spherical and Cylindrical Capacitors
- Capacitors in Parallel and Series
- Energy Stored in an Electric Field
- Atomic Physics View of Dielectrics
- Electric Dipole in an Electric Field
- Capacitors with a Dielectric
- Dielectrics and Gauss Law
- Summary

What Capacitance Measures

How much charge does an arrangement of conductors hold when a given voltage is applied? The charge needed, depends on a geometrical $\mathbf{Q} = \mathbf{C} \wedge \mathbf{V}$

 The charge needed depends on a geometrical factor called capacitance.

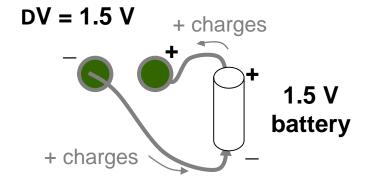
Example:

- Two conducting spheres: Radii R_1 and $R_2 = 2R_1$. Different charges Q_1 and Q_2 .
- Spheres touch and come to the same potential ΔV ,
- Apply point charge potential formula, V(infinity) = 0

$$\Delta V = \frac{1}{4\pi\epsilon_0} \frac{Q_1}{R_1} \equiv \frac{Q_1}{C_1} \text{ and also } \Delta V = \frac{1}{4\pi\epsilon_0} \frac{Q_2}{R_2} \equiv \frac{Q_2}{C_2} \quad \longrightarrow \quad \frac{Q_1}{Q_2} \equiv \frac{C_1}{C_2} = \frac{R_1}{R_2} = \frac{1}{2}$$
Capacitance of a single isolated sphere: $C = 4\pi\epsilon_0 R$

Example: A primitive capacitor

- The right ball's potential is the same as the + side of the battery. Similarly for the ball.
- How much charge flows onto each ball to produce a potential difference of 1.5 V ?
- The answer depends on the capacitance.

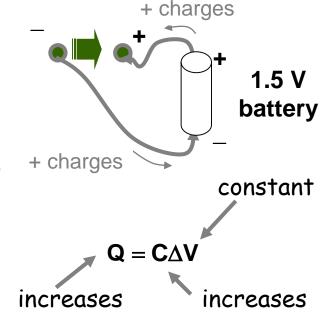


Definition of CAPACITANCE :	$C \equiv \frac{Q}{\Delta V}$ or $Q \equiv C \Delta V$	[Coulombs]
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- Measures the charge needed per volt of potential difference
- Does not depend on applied DV or charge Q. Always positive.
- Depends on geometry (and on dielectric materials) only
- Units: 1 *FARAD* = 1 Coulomb / Volt. Farads are very large 1 mF = 10⁻⁶ F. 1 pF = 1 pico-Farad = 10^{-12} F = 10^{-6} µF = 1 µµF

Example - Capacitance depends on geometry

- Move the balls at the ends of the wires closer together while still connected to the battery
- The potential difference ΔV cannot change.
- But: $\Delta V = -\int \vec{E} \cdot d\vec{s} \approx \vec{E}_{av} \circ \Delta \vec{s}$
- The distance Ds between the balls decreased so the E field had to increase as did the stored energy.
- Charge flowed from the battery to the balls to increase E.
- The two balls now hold more charge for the same potential difference: i.e. the capacitance increased.

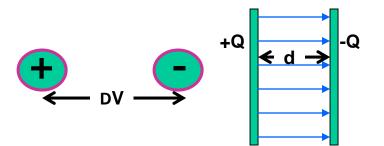


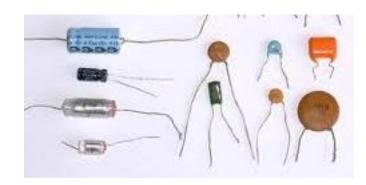
Capacitors are charge storage devices

- Two conductors not in electrical contact
- Electrically neutral before & after being charged

 $Q_{enc} = Q_{net} = 0$

- Current can flow from + plate to plate if there is a conducting path (complete circuit)
- Capacitors store charge and potential energy
 - memory bits radio circuits power supplies
- Common type: "parallel plate", sometimes tubular





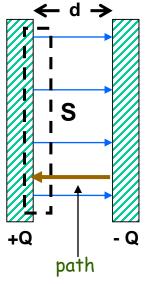
Method for calculating capacitance from geometry:

- Assume two conducting plates (equipotentials) with equal and opposite charges +Q and –Q
- Possibly use Gauss' Law to find E between the plates
- Calculate ΔV between plates using a convenient path
- Capacitance $C = Q/\Delta V$
- Certain materials ("dielectrics") can reduce the E field ΔV_{fi} = -J E ° GS
 between plates by "polarizing" capacitance increases^{Copyright R. Janow Fall 2013}

$$\Phi_{\rm E} = \frac{{\bf q}_{\rm enc}}{{\boldsymbol \varepsilon}_{\rm 0}} = \oint_{\rm S} \vec{{\bf E}} \circ {\bf d} \vec{{\bf A}}$$

$$\Delta V_{fi} = -\int_{\cdot}^{t} \vec{E} \circ d\vec{s}$$

EXAMPLE: CALCULATE C for a PARALLEL PLATE CAPACITOR





- A = plate area. Treat plates as infinite sheets
- $|s^+| = |-s^-| = s = Q / A = uniform surface charge density$
- E is uniform between the plates (d << plate size)
- Use Gaussian surface S (one plate). Flux through ends and attached conductors is zero. Total flux is EA

A₀3

•
$$Q_{enc} = \sigma A = e_0 t = \varepsilon_0 EA$$

• $Q_{enc} = \sigma A = e_0 t = \varepsilon_0 EA$
 $\therefore E = \sigma/\varepsilon_0 \quad i.e., E = Q/\varepsilon_0 A$
(infinite conducting sheet)
• Choose V = 0 on negative plate (grounded)
• Choose path from - plate to + plate, opposite to E field
 $\Delta V_{fi} = -\int \vec{E} \circ d\vec{s} = (-)(-)Ed = +\frac{\sigma}{\varepsilon_0} d = \frac{Qd}{\varepsilon_0 A} = \frac{Q}{C}$

$$\therefore \ \mathbf{C} \equiv \frac{\mathbf{Q}}{\Delta \mathbf{V}} = \frac{\varepsilon_0 \mathbf{A}}{\mathbf{d}} \quad \begin{array}{l} \cdot \mathbf{C} \text{ DEPENDS ONLY ON GEOMETRY} \\ \cdot \mathbf{C} \Rightarrow \text{ infinity as plate separation } \mathbf{d} \Rightarrow \mathbf{0} \\ \cdot \mathbf{C} \text{ directly proportional to plate area } \mathbf{A} \end{array}$$

Other formulas for other geometries

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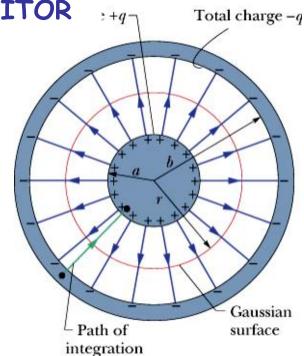
insulation

EX 24.03: FIND C for a SPHERICAL CAPACITOR

- 2 concentric spherical, conducting shells, radii a & b
- Charges are +q (inner sphere), -q (outer sphere)
- All charge on the outer sphere is on its inner surface (by Gauss's Law)
- Choose Gaussian surface S as shown and find field using Gauss's Law:

$$\varepsilon_0 \int_{s} \vec{E} \cdot d\vec{A} = q$$
 $q = \varepsilon_0 EA = \varepsilon_0 E(4\pi r^2)$

- As before: $E = q/(4\pi\epsilon_0 r^2)$
- To find potential difference use outward radial integration path from r = a to r = b.



$$\Delta \mathbf{V} = \mathbf{V}_{b} - \mathbf{V}_{a} = -\int_{r=a}^{r=b} \vec{\mathbf{E}} \cdot d\vec{\mathbf{S}} = \frac{-\mathbf{q}}{4\pi\varepsilon_{0}} \int_{r=a}^{r=b} \frac{d\mathbf{r}}{\mathbf{r}^{2}} = \frac{-\mathbf{q}}{4\pi\varepsilon_{0}} \frac{(-)\mathbf{1}}{\mathbf{r}} \Big|_{a}^{b}$$
$$\Delta \mathbf{V} = \frac{\mathbf{q}}{4\pi\varepsilon_{0}} \left(\frac{\mathbf{1}}{b} - \frac{\mathbf{1}}{a}\right) = \frac{\mathbf{q}}{4\pi\varepsilon_{0}} \left(\frac{\mathbf{a} - \mathbf{b}}{ba}\right) \quad \begin{array}{l} \text{Negative} \\ \text{For } \mathbf{b} > \mathbf{a} \end{array} \quad \mathbf{V}_{b} < \mathbf{V}_{a}$$

$$\therefore \mathbf{C} \equiv \frac{\mathbf{q}}{|\Delta \mathbf{V}|} = \frac{4\pi\varepsilon_0 \mathbf{a}\mathbf{b}}{\mathbf{b} - \mathbf{a}}$$

Let $b \rightarrow$ infinity. Then $a/b \rightarrow 0$ and result becomes the earlier formula for the isolated sphere:

$$C \rightarrow \frac{4\pi\varepsilon_0 ab}{b} = 4\pi\varepsilon_0 a$$
 ¹³

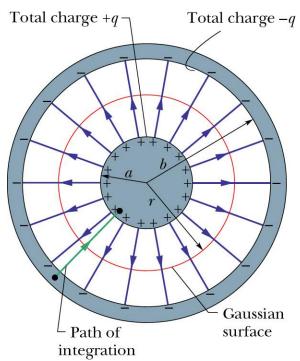
EX 24.04: Find C for a CYLINDRICAL CAPACITOR

- 2 concentric, long cylindrical conductors
- Radii a & b and length L >> b => neglect end effects
- $\boldsymbol{\cdot}$ Charges are +q (inner) and -q (outer), $\boldsymbol{\lambda}$ is uniform
- All charge on the outer conductor is on its inner surface (by Gauss's Law)
- Choose Gaussian surface S between plates and find field at radius r.
- E is perpendicular to endcaps => zero flux contribution

$$\varepsilon_0 \Phi_{cyl} = \varepsilon_0 \int_{s} \vec{E} \cdot d\vec{A} = q$$
 $q = \varepsilon_0 EA = \varepsilon_0 E(2\pi rL)$

• So:
$$\mathbf{E} = \mathbf{q}/(2\pi\varepsilon_0 \mathbf{r}\mathbf{L}) = \lambda/(2\pi\varepsilon_0 \mathbf{r})$$

• To find potential difference use outward radial integration path from r = b to r = a.



$$\Delta V = V_{b} - V_{a} = -\int_{r=a}^{r=b} \vec{E} \cdot d\vec{s} = \frac{-q}{2\pi\varepsilon_{0}L} \int_{r=a}^{r=b} \frac{dr}{r} = \frac{-q}{2\pi\varepsilon_{0}L} \ln(r) \Big|_{a}^{b} = \frac{-q}{2\pi\varepsilon_{0}L} \ln(b/a)$$

$$C = q/\Delta V = 2\pi \varepsilon_0 \frac{L}{\ln(b/a)}$$

 $C \rightarrow 0$ as b/a \rightarrow inf $C \rightarrow$ inf as b/a $\rightarrow 1$ $V_b < V_a$ For b > a

C depends only on geometrical parameters Copyright R. Janow – Fall 2013

Examples of Capacitance Formulas



- Units: F (Farad) = C²/Nm = C/ Volt = $\varepsilon_0 \times \text{length}$
 - named after Michael Faraday. [note: $\varepsilon_0 = 8.85 \text{ pF/m}$]

All of these formulas depend only on geometrical factors

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Capacitors in circuits

CIRCUIT SYMBOLS:

CIRCUIT DEFINITIONS:

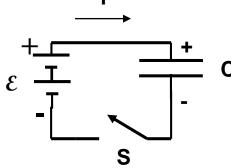
 $Current \equiv i \equiv dq/dt$

= rate of + charge flow past a point in the circuit

Open Circuit: NO closed path. No current. Conductors are equi-potentials Closed Circuit: There is/are completed paths through which current can flow. Loop Rule: Potential is a conservative field

 \rightarrow Potential CHANGE around ANY closed path = 0

Example: CHARGING A CAPACITOR



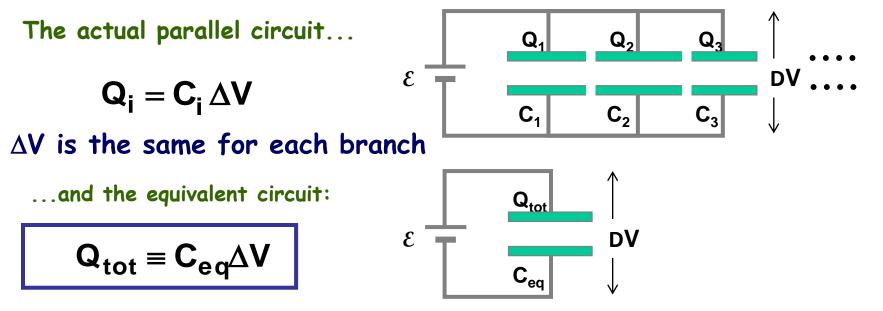
- Current flows when switch is CLOSED, completing circuit
- Battery (EMF) maintains DV (= EMF ε), and supplies energy by moving free + charges from – to + terminal, internal to battery
- Convention: i flows from + to outside of battery When switch closes, current (charge) flows until DV across capacitor equals battery voltage E. Then current stops as E field in wire → 0

DEFINITION: EQUIVALENT CAPACITANCE

• Capacitors can be connected in series, parallel, or more complex combinations

- The "equivalent capacitance" is the capacitance of a SINGLE capacitor that would have the same capacitance as the combination.
- The equivalent capacitance can replace the original combination in analysis.

Parallel capacitors - Equivalent capacitance



The parallel capacitors are just like a single capacitor with larger plates so....

 $Q_{tot} = \sum Q_i$ (parallel)

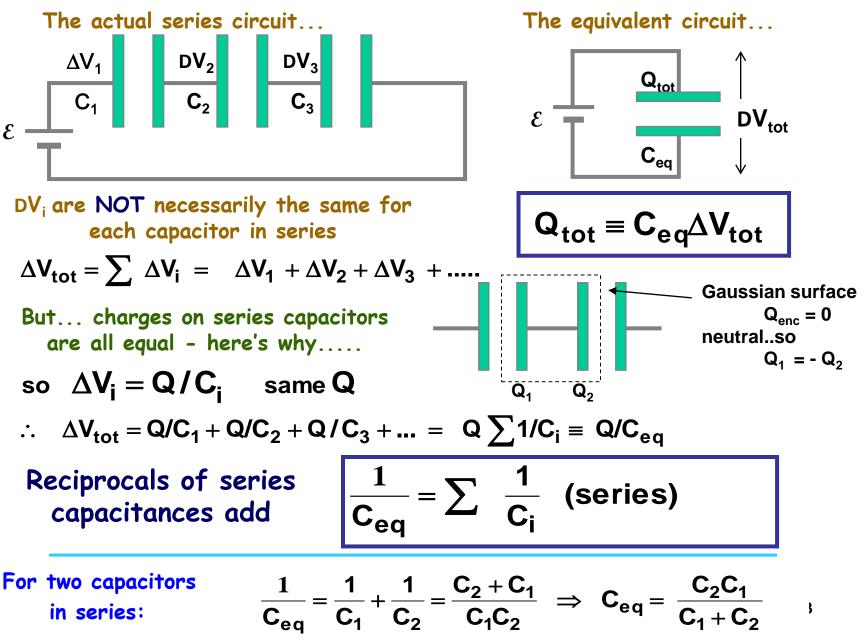
Charges on parallel capacitors add

$$\therefore \quad Q_{tot} = C_1 \Delta V + C_2 \Delta V + C_3 \Delta V + ... = (C_1 + C_2 + C_3 + ...) \Delta V$$
Parallel capacitances add directly
$$C_{eq} = \sum C_i \quad \text{(parallel)}$$

Question: Why is DV the same for all elements in parallel? Answer: Potential is conservative field, for ANY closed loop around circuit:

 $\sum \Delta V_i = 0$ (KirchoffLoopRule)

Series capacitors - equivalent capacitance



Example 1: A 33 μ F and a 47 μ F capacitor are connected in parallel Find the equivalent capacitance Solution: $C_{para} = C_1 + C_2 = 80 \mu$ F

Example 2: Same two capacitors as above, but now in series connection

Solution:
$$C_{ser} = \frac{C_1 C_2}{C_1 + C_2} = \frac{33 \times 47}{33 + 47} = 19.4 \ \mu F$$

Example 3:

A pair of capacitors is connected as shown

- $C_1 = 10 \ \mu$ F, charged initially to $100V = V_i$
- $C_2 = 20 \ \mu$ F, uncharged initially

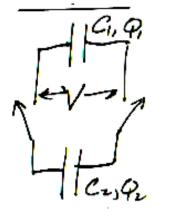
Close switches. Find final potentials across C₁ & C₂. Solution:

- · C's are in parallel \rightarrow Same potential V_f for each
- Total initial charge: $Q_{tot} = Q_{1i} = C_1 V_i = 10^{-3} C.$
- Charge is conserved it redistributes on both C_1 & C_2 10^{-3}

Ceq =
$$Q_{tot} / V_f = C_1 + C_2 \implies V_f = \frac{10}{30 \times 10^{-6}} = 33 V_f$$

Final charge on each:

$$\mathbf{Q}_{1f} = \ \mathbf{C}_1 \ \mathbf{V}_f \ = 3.3 \ x \ 10^{-4} \ \mathbf{C}. \quad \mathbf{Q}_{2f} = \ \mathbf{C}_2 \ \mathbf{V}_f \ = 6.7 \ x \ 10^{-4} \ \mathbf{C}.$$



Three Capacitors in Series

6-2: The equivalent capacitance for two capacitors in series is: 1 C₁C₂

$$C_{eq} = \frac{1}{\frac{1}{C_1} + \frac{1}{C_2}} = \frac{C_1 C_2}{C_1 + C_2}$$

Which of the following is the equivalent capacitance formula for three capacitors in series?

A.
$$C_{eq} = \frac{C_1 C_2 C_3}{C_1 + C_2 + C_3}$$

Β.

С.

$$C_{eq} = \frac{C_1 C_2 + C_2 C_3 + C_1 C_3}{C_1 + C_2 + C_3}$$
$$C_{eq} = \frac{C_1 C_2 + C_2 C_3 + C_3 C_1}{C_1 C_2 C_3}$$

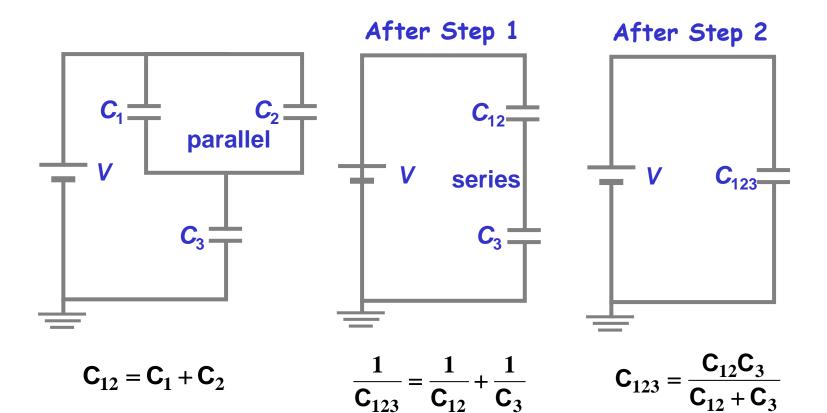
C_{eq} =
$$\frac{C_1 + C_2 + C_3}{C_1 C_2 C_3}$$

E.

$$C_{eq} = \frac{C_1 C_2 C_3}{C_1 C_2 + C_2 C_3 + C_3 C_1}$$

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Example: Reduce circuit to find $C_{eq}=C_{123}$ for mixed series-parallel capacitors



Values:

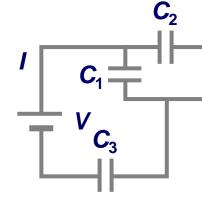
$$C_1 = 12.0 \ \mu\text{F}, \ C_2 = 5.3 \ \mu\text{F}, \ C_3 = 4.5 \ \mu\text{F}$$

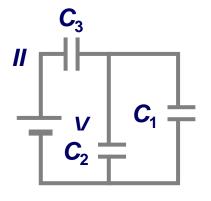
 $C_{123} = (12 + 5.3) 4.5 / (12 + 5.3 + 4.5) \mu F = 3.57 \mu F$ Copyright R. Janow – Fall 2013

Series or Parallel?

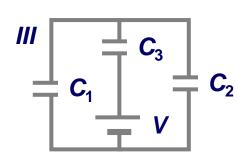
6-3: In the circuits below, which ones show capacitors 1 and 2 connected in series?

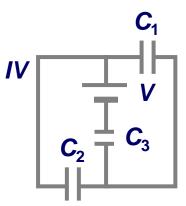
- A. I, II, III
- B. I, III
- C. II, IV
- D. III, IV
- E. None





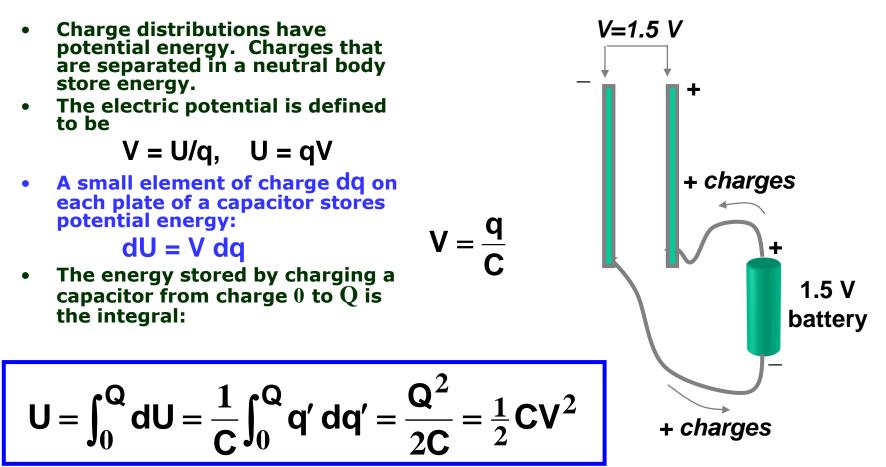






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Energy Stored in a Capacitor When charge flows in the sketch, energy stored in the battery is depleted. Where does it go?



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Capacitors Store Energy in the Electrostatic Field

• The total energy in a parallel plate capacitor is

$$\mathbf{U} = \frac{1}{2}\mathbf{C}\mathbf{V}^2 = \frac{\varepsilon_0\mathbf{A}}{2\mathbf{d}}\mathbf{V}^2$$

• The volume of space filled by the electric field in the capacitor is = Ad, so the *energy density u* is

$$\mathbf{u} \equiv \frac{\mathbf{U}}{\mathbf{vol}} = \frac{\varepsilon_0 \mathbf{A}}{2\mathbf{dAd}} \mathbf{V}^2 = \frac{1}{2} \varepsilon_0 \left(\frac{\mathbf{V}}{\mathbf{d}}\right)^2$$



• But for a parallel plate capacitor,

$$V = -\int \vec{E} \cdot d\vec{s} = Ed$$

$$\mathbf{U} = \frac{1}{2} \boldsymbol{\epsilon}_0 \mathbf{E}^2$$

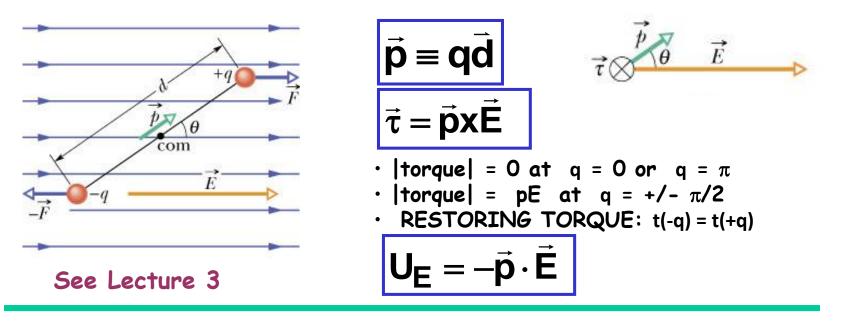


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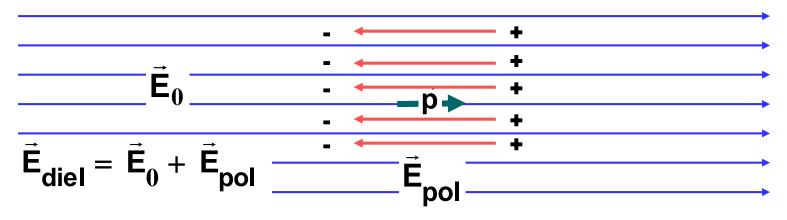
Model for a Molecule that can Polarize

A dipole in a uniform external field..

.. feels torque, stores electrostatic potential energy

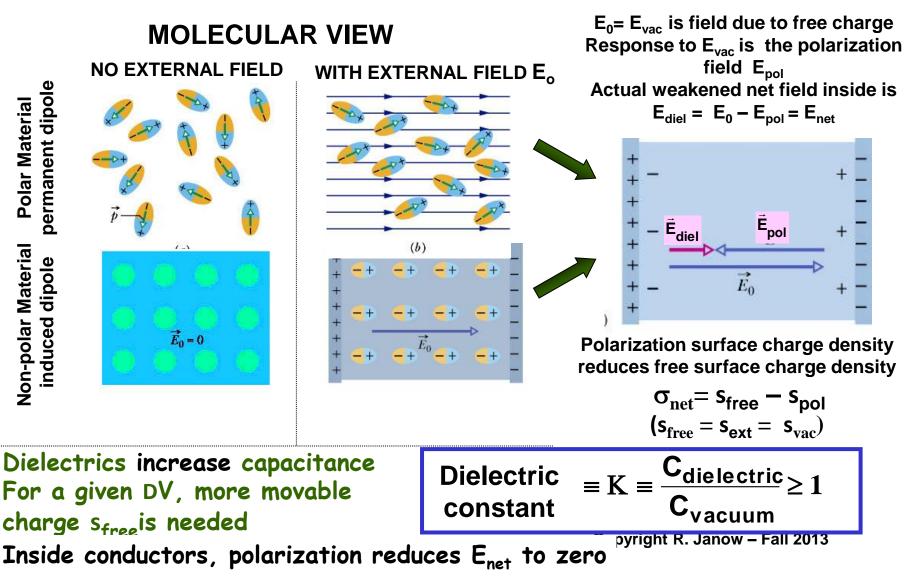


Polarization: An external field aligns dipoles in a material, causing polarization that reduces the field



Dielectric materials in capacitors

- Insulators POLARIZE when an external electric field is applied
- The NET field inside the material is reduced.



Representing Dielectrics

- \mathcal{E}_0 is the free space permittivity.
- All materials (water, paper, plastic, air) polarize to some extent and have different permittivities ε = κε₀
- K is the *dielectric constant* a dimensionless number.
- Wherever you see \mathcal{E}_{0} for a vacuum, you can substitute $\mathcal{K}\mathcal{E}_{0}$ when considering dielectric materials.
- For example, the capacitance of a parallel plate capacitor increases when the space is filled with a dielectric:

$$\mathbf{C}_{diel} = \frac{\kappa \varepsilon_0 \mathbf{A}}{\mathbf{d}} = \kappa \mathbf{C}_{vac}$$

• A dielectric weakens the field, compared to what it would be for a vacuum

$$\vec{\mathsf{E}}_{diel} = \vec{\mathsf{E}}_{vac}/\kappa \equiv \vec{\mathsf{D}}/\varepsilon_0\kappa$$

TABLE 26.1

Approximate Dielectric Constants and Dielectric Strengths of Various Materials at Room Temperature

Material	Dielectric Constant <i>ĸ</i>	Dielectric Strength ^a (10 ⁶ V/m)
Air (dry)	1.00059	3
Bakelite	4.9	24
Fused quartz	3.78	8
Mylar	3.2	7
Neoprene rubber	6.7	12
Nylon	3.4	14
Paper	3.7	16
Paraffin-impregnated paper	3.5	11
Polystyrene	2.56	24
Polyvinyl chloride	3.4	40
Porcelain	6	12
Pyrex glass	5.6	14
Silicone oil	2.5	15
Strontium titanate	233	8
Teflon	2.1	60
Vacuum	$1.000\ 00$	
Water	80	%

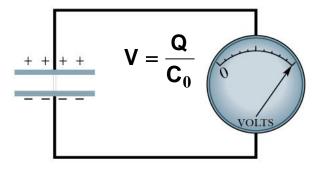
^a The dielectric strength equals the maximum electric field that can exist in a dielectric without electrical breakdown. These values depend strongly on the presence of impurities and flaws in the materials.

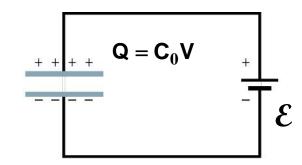
What happens as you insert a dielectric?

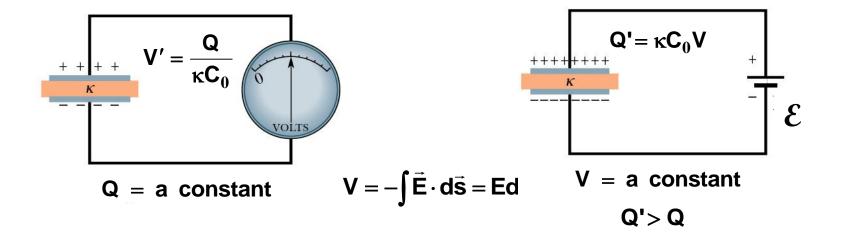
Initially, charge capacitor C_0 to voltage V, charge Q, field E_{net} .

- With battery detached insert dielectric
- Q remains constant, E_{net} is reduced
- Voltage (fixed Q) drops to V'.
- Dielectric reduced E_{net} and V.

- With battery attached, insert dielectric.
- E_{net} and V are momentarily reduced but battery maintains voltage *E*
- Charge flows to the capacitor as dielectric is inserted until V and E_{net} are back to original values.







OR

Gauss' Law with a dielectric

$$\epsilon_0 \int_{S} \vec{E}_{diel} \circ d\vec{A} = q_{free} - q_{pol} = q_{net}$$

OPTIONAL TOPIC

Alternatively:

$$\int_{S} \varepsilon_{0} \vec{E}_{vac} \circ d\vec{A} = q_{free} = \int_{S} \varepsilon_{0} K \vec{E}_{diel} \circ d\vec{A} \equiv \int_{S} \vec{D} \circ d\vec{A}$$

free charge on plates
field not counting polarization = $\varepsilon_{0} E_{vac}$

The "Electric Displacement" D measures field that would be present due to the "free" charge only, i.e. without polarization field from dielectric

$$\mathbf{E}_{vac} = \mathbf{K}\mathbf{E}_{diel} \qquad \mathbf{D} \equiv \varepsilon_0 \mathbf{E}_{vac} = \varepsilon_0 \mathbf{K}\mathbf{E}_{diel} \equiv \varepsilon \mathbf{E}_{diel}$$

- K could vary over Gaussian surface S. Usually it is constant and factors
- Flux is still measured using field without dielectric: $E_{vac} = KE_{diel} = D/e_0$)

$$d\Phi = \vec{E}_{vac} \circ d\vec{A} = KE_{diel} \circ d\vec{A}$$

- Only the free charges q_{free} (excluding polarization) are counted as q_{enc} in the above. Using K on the left compensates for the polarization.
- When applying the above include only q_{free}.
 Ignore polarization charges inside the Gaussian surface

Summary: Chapter 25: Capacitance

 $C = \frac{Q}{V_{ab}}$

 $C = \frac{Q}{V_{L}} = \epsilon_0 \frac{A}{d}$

Lecture 6

CHAPTER 24 SUMMARY

Capacitors and capacitance: A capacitor is any pair of conductors separated by an insulating material. When the capacitor is charged, there are charges of equal magnitude Q and opposite sign on the two conductors, and the potential V_{ab} of the positively charged conductor with respect to the negatively charged conductor is proportional to Q. The capacitance C is defined as the ratio of Q to V_{ab} . The SI unit of capacitance is the farad (F): 1 F = 1 C/V.

A parallel-plate capacitor consists of two parallel conducting plates, each with area A, separated by a distance d. If they are separated by vacuum, the capacitance depends only on A and d. For other geometries, the capacitance can be found by using the definition $C = Q/V_{ab}$. (See Examples 24.1–24.4.)

Capacitors in series and parallel: When capacitors with capacitances C_1, C_2, C_3, \ldots are connected in series, the reciprocal of the equivalent capacitance C_{eq} equals the sum of the reciprocals of the individual capacitances. When capacitors are connected in parallel, the equivalent capacitance C_{eq} equals the sum of the individual capacitances. (See Examples 24.5 and 24.6.)

$$\frac{1}{C_{eq}} = \frac{1}{C_1} + \frac{1}{C_2} + \frac{1}{C_3} + \cdots$$
(capacitors in series)
$$C_{eq} = C_1 + C_2 + C_3 + \cdots$$
(capacitors in parallel)
(24.7)
$$\frac{1}{V_{ab}} = V + \frac{1}{C_2} + \frac{1}{C_3} + \cdots$$
(24.7)

(24.1) (24.2) Potential difference = V_{ab} Wire Plate *a*, area *A d* Plate *b*, area *A*

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Energy in a capacitor: The energy U required to charge a capacitor C to a potential difference V and a charge Q is equal to the energy stored in the capacitor. This energy can be thought of as residing in the electric field between the conductors; the energy density u (energy per unit volume) is proportional to the square of the electric-field magnitude. (See Examples 24.7–24.9.)

(24.19)

.20)

Dielectrics: When the space between the conductors is filled with a dielectric material, the capacitance increases by a factor *K*, called the dielectric constant of the material. The quantity $\epsilon = K\epsilon_0$ is called the permittivity of the dielectric. For a fixed amount of charge on the capacitor plates, induced charges on the surface of the dielectric decrease the electric field and potential difference between the plates by the same factor *K*. The surface charge results from polarization, a microscopic rearrangement of charge in the dielectric. (See Example 24.10.)

Under sufficiently strong fields, dielectrics become conductors, a situation called dielectric breakdown. The maximum field that a material can withstand without breakdown is called its dielectric strength.

In a dielectric, the expression for the energy density is the same as in vacuum but with ϵ_0 replaced by $\epsilon = K\epsilon$. (See Example 24.11.)

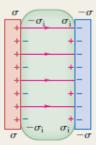
Gauss's law in a dielectric has almost the same form as in vacuum, with two key differences: \vec{E} is replaced by $K\vec{E}$ and Q_{encl} is replaced by $Q_{encl-free}$, which includes only the free charge (not bound charge) enclosed by the Gaussian surface. (See Example 24.12.) $C = KC_0 = K\epsilon_0 \frac{A}{d} = \epsilon \frac{A}{d}$ (parallel-plate capacitor

filled with dielectric)

$$u = \frac{1}{2}K\epsilon_0 E^2 = \frac{1}{2}\epsilon E^2 \tag{24}$$

$$\oint K\vec{E} \cdot d\vec{A} = \frac{Q_{\text{encl-free}}}{\epsilon_0}$$
(24.23)

Dielectric between plates



809